

Excellent Integrated System Limited

Stocking Distributor

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<u>Vishay Semiconductor/Diodes Division</u> <u>VS-25TTS12FPPBF</u>

For any questions, you can email us directly: sales@integrated-circuit.com

Distributor of Vishay Semiconductor/Diodes Division: Excellent Integrated System Limite Datasheet of VS-25TTS12FPPBF - SCR PHASE CTRL 1200V 25A TO220FP

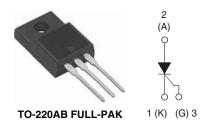
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25TTS...FPPbF High Voltage Series

Vishay High Power Products

Phase Control SCR TO-220AB FULL-PAK, 25 A



PRODUCT SUMMARY		
V _T at 16 A < 1.25 V		
I _{TSM}	200 A	
V _{RRM}	800/1200 V	

DESCRIPTION/FEATURES

The 25TTS...FPPbF High Voltage Series of silicon controlled rectifiers are specifically designed for medium power switching and phase control applications. The glass passivation technology used has reliable operation up to 140 °C junction temperature.

Typical applications are in input rectification (soft start) and these products are designed to be used with Vishay HPP input diodes, switches and output rectifiers which are available in identical package outlines. Fully isolated package ($V_{INS} = 2500 \ V_{RMS}$); plastic material $94V_{Ro}$.

This product has been designed and qualified for industrial level and lead (Pb)-free ("PbF" suffix).

OUTPUT CURRENT IN TYPICAL APPLICATIONS				
APPLICATIONS	SINGLE-PHASE BRIDGE	THREE-PHASE BRIDGE	UNITS	
Capacitive input filter $T_A = 55$ °C, $T_J = 125$ °C, common heatsink of 1 °C/W	18	22	А	

MAJOR RATINGS AND CHARACTERISTICS				
PARAMETER	TEST CONDITIONS	VALUES	UNITS	
I _{T(AV)}	Sinusoidal waveform	16	A	
I _{RMS}		25	A	
V _{RRM} /V _{DRM}		800/1200	V	
I _{TSM}		300	А	
V _T	16 A, T _J = 25 °C	1.25	V	
dV/dt		500	V/µs	
dl/dt		150	A/µs	
TJ		- 40 to 125	°C	

VOLTAGE RATINGS						
PART NUMBER	V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V _{DRM} , MAXIMUM PEAK DIRECT VOLTAGE V	I _{RRM} /I _{DRM} AT 125 °C mA			
25TTS08FPPbF	800 800					
25TTS12FPPbF	1200	1200	10			

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^{*} Pb containing terminations are not RoHS compliant, exemptions may apply

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ABSOLUTE MAXIMUM RATINGS				
	SYMBOL	TEST COMPITIONS	VALUES	UNITS
PARAMETER		TEST CONDITIONS	TYP. MAX.	UNITS
Maximum average on-state current	I _{T(AV)}	T _C = 85 °C, 180° conduction half sine wave	16	
Maximum RMS on-state current	I _{RMS}		25	A
Maximum peak, one-cycle,	1	10 ms sine pulse, rated V _{RRM} applied	300	_ A
non-repetitive surge current	I _{TSM}	10 ms sine pulse, no voltage reapplied	350	
Maximum I ² t for fusing	l ² t	10 ms sine pulse, rated V _{RRM} applied	450	A ² s
Maximum i-t for fusing	I ² t	10 ms sine pulse, no voltage reapplied	630	A-5
Maximum I ² √t for fusing	I ² √t	t = 0.1 to 10 ms, no voltage reapplied	6300	A ² √s
Maximum on-state voltage drop	V_{TM}	16 A, T _J = 25 °C	1.25	V
On-state slope resistance	r _t	T 105 °C	12.0	mΩ
Threshold voltage	V _{T(TO)}	T _J = 125 °C	1.0	V
Maximum various and divest lacks as a current	1 /1	T _J = 25 °C	0.5	
Maximum reverse and direct leakage current	I_{RM}/I_{DM}	T _J = 125 °C V _R = Rated V _{RRM} /V _{DRM}	10	mA
Holding current	I _H	Anode supply = 6 V, resistive load, initial $I_T = 1 A$	- 100	IIIA
Maximum latching current	ΙL	Anode supply = 6 V, resistive load	200	
Maximum rate of rise of off-state voltage	dV/dt		500	V/µs
Maximum rate of rise of turned-on current	dI/dt		150	A/µs

TRIGGERING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum peak gate power	P _{GM}		8.0	W
Maximum average gate power	P _{G(AV)}		2.0] *
Maximum peak positive gate current	+ I _{GM}		1.5	Α
Maximum peak negative gate voltage	- V _{GM}		10	V
	I _{GT}	Anode supply = 6 V, resistive load, T _J = - 10 °C	60	mA
Maximum required DC gate current to trigger		Anode supply = 6 V, resistive load, T _J = 25 °C	45	
		Anode supply = 6 V, resistive load, T _J = 125 °C	20	1
Maximum required DC gate voltage to trigger	V _{GT}	Anode supply = 6 V, resistive load, T _J = - 10 °C	2.5	
		Anode supply = 6 V, resistive load, T _J = 25 °C	2.0	
		Anode supply = 6 V, resistive load, T _J = 125 °C	1.0	\ \ \
Maximum DC gate voltage not to trigger	V_{GD}	$T_J = 125$ °C, $V_{DRM} = $ Rated value 0.25		
Maximum DC gate current not to trigger	I _{GD}			mA

SWITCHING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Typical turn-on time	t _{gt}	T _J = 25 °C	0.9	
Typical reverse recovery time	t _{rr}	T 405 °C	4	μs
Typical turn-off time	tq	T _J = 125 °C	110	



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THERMAL AND MECHANICAL SPECIFICATIONS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range		T _J , T _{Stg}		- 40 to 125	°C
Maximum thermal resistance, junction to case		R_{thJC}	DC operation	1.5	
Maximum thermal resistance, junction to ambient		R_{thJA}		62	°C/W
Typical thermal resistance, case to heatsink		R_{thCS}	Mounting surface, smooth and greased	1.5	
Approximate weight				2	g
Approximate weight				0.07	oz.
Mounting torque ————	minimum			6 (5)	kgf · cm
	maximum			12 (10)	(lbf · in)
Mading decise		O TO TO SOO AD FILL DAY (OAA)	25TTS08FP		
Marking device			Case style TO-220AB FULL-PAK (94/V0)	25TTS1:	2FP

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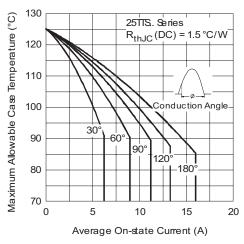


Fig. 1 - Current Rating Characteristics

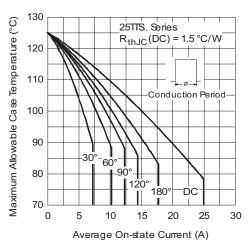


Fig. 2 - Current Rating Characteristics

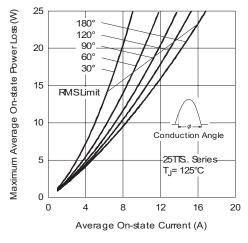


Fig. 3 - On-State Power Loss Characteristics

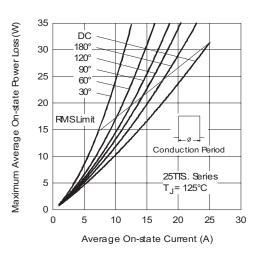


Fig. 4 - On-State Power Loss Characteristics

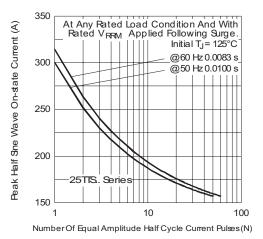


Fig. 5 - Maximum Non-Repetitive Surge Current

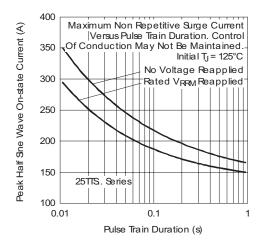


Fig. 6 - Maximum Non-Repetitive Surge Current



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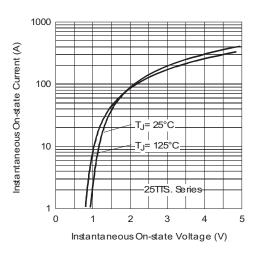


Fig. 7 - On-State Voltage Drop Characteristics

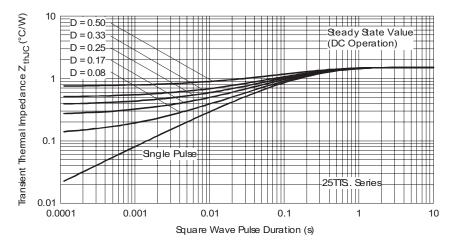


Fig. 8 - Thermal Impedance Z_{thJC} Characteristics

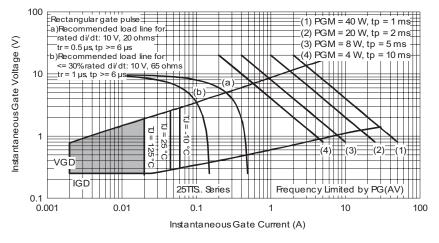


Fig. 9 - Gate Characteristics

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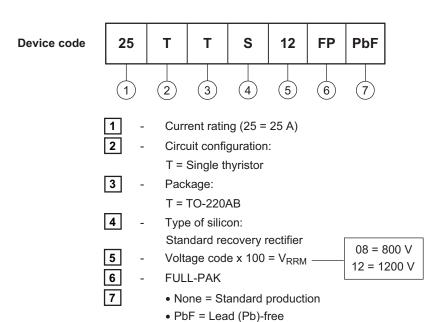
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ORDERING INFORMATION TABLE



LINKS TO RELATED DOCUMENTS				
Dimensions http://www.vishay.com/doc?95072				
Part marking information	http://www.vishay.com/doc?95069			



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